

High voltage fast-switching NPN power transistor

Features

- High voltage capability
- Very high switching speed

Application

■ Electronic ballast for fluorescent lighting

Description

The device is manufactured using high voltage multi epitaxial planar technology for high switching speeds and high voltage capability. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA. The ST83003 is expressly designed for a new solution to be used in compact fluorescent lamps, where it is coupled with the ST93003, its complementary PNP transistor.

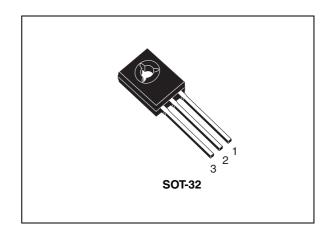


Figure 1. Internal schematic diagram

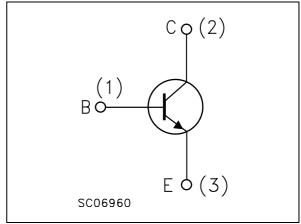


Table 1. Device summary

Order code Marking		Package	Packaging
ST83003 83003		SOT-32	Bag

Contents ST83003

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ST83003 Electrical ratings

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CES}	Collector-emitter voltage (V _{BE} = 0)	700	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	400	V
V _{EBO}	Emitter-base voltage $(I_C = 0, I_B = 0.75 \text{ A}, t_p < 10 \mu\text{s})$	V _{(BR)EBO}	V
I _C	Collector current	1.5	Α
I _{CM}	Collector peak current (t _p < 5 ms)	3	Α
I _B	Base current	0.75	Α
I _{BM}	Base peak current (t _p < 5 ms)	1.5	Α
P _{TOT}	Total dissipation at T _c = 25 °C	40	W
T _{STG}	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thJC}	Thermal resistance junction-case max	3.1	°C/W

Electrical characteristics ST83003

2 Electrical characteristics

 $T_{case} = 25$ °C unless otherwise specified

Table 4. On/off states

Symbol	Parameter	Test conditions	Value			Unit
Syllibol			Min.	Тур.	Max.	Jilit
I _{CES}	Collector cut-off current (V _{BE} = 0)	V _{CE} = 700 V V _{CE} = 700 V, T _C = 125 °C			1 5	mA mA
V _{(BR)EBO}	Emitter-base breakdown voltage (I _C = 0)	I _E = 10 mA	12		18	٧
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage (I _B = 0)	I _C = 10 mA	400			V
V _{CE(sat)} (1)	Collector-emitter saturation voltage	$I_C = 0.5 \text{ A}, I_B = 0.1 \text{ A}$ $I_C = 0.35 \text{ A}, I_B = 50 \text{ mA}$			0.5 1	V V
V _{BE(sat)} (1)	Base-emitter saturation voltage	I _C = 0.5 A, I _B = 0.1 A			1	V
h _{FE} ⁽¹⁾	DC current gain	$I_C = 10 \text{ mA}, V_{CE} = 5 \text{ V}$ $I_C = 0.35 \text{ A}, V_{CE} = 5 \text{ V}$ $I_C = 1 \text{ A}, V_{CE} = 5 \text{ V}$	10 16 4	25	32	
t _r t _s	Resistive load Rise time Storage time Fall time	I_{C} = 0.35 A, V_{CC} = 125 V, I_{B1} = 70 mA, I_{B2} = -70 mA $I_{P} \ge$ 25 μ s see <i>Figure 14</i>	1.5	100 2.2 0.2	2.9	ns µs µs
t _s t _f	Inductive load Storage time Fall time	$I_{C} = 0.5 \text{ A}, I_{B1} = 0.1 \text{ A},$ $V_{BE(off)} = -5 \text{ V},$ $L = 10 \text{ mH}, V_{clamp} = 300 \text{ V}$ see <i>Figure 13</i>		450 90		ns ns

^{1.} Pulse test: pulse duration \leq 300 μ s, duty cycle \leq 2 %

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

Ic(A)

A = Area of permissible operation driving turn-on provided R_{BE} = 100 Ohm and tr≤ 100ns

10¹

B | Ic MAX | PULSE OPERATION *

PULSED | 100µs | 100µs

Figure 3. Derating

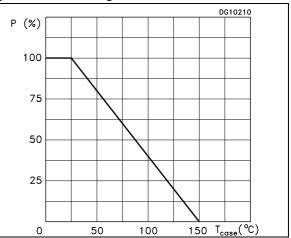


Figure 4. DC current gain $(V_{CE} = 5 V)$

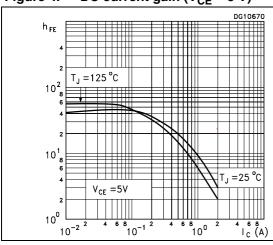


Figure 5. DC current gain $(V_{CE} = 1 V)$

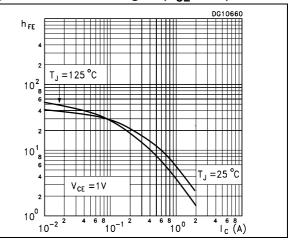
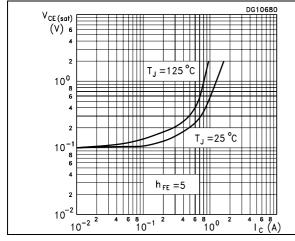
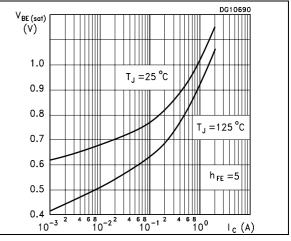


Figure 6. Collector emitter saturation voltage Figure 7. Base emitter saturation voltage

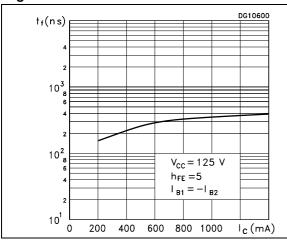




Electrical characteristics ST83003

Figure 8. Resistive load fall time

Figure 9. Resistive load storage time



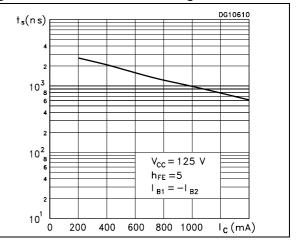
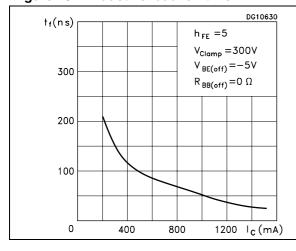


Figure 10. Inductive load fall time

Figure 11. Inductive load storage time



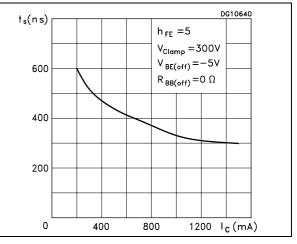
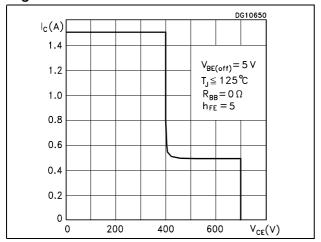


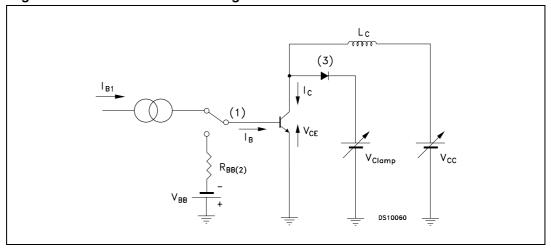
Figure 12. Reverse biased SOA



ST83003 Test circuits

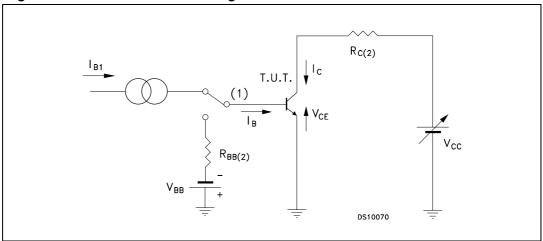
3 Test circuits

Figure 13. Inductive load switching



- 1. Fast electronic switch
- 2. Non-inductive resistor
- 3. Fast recovery rectifier

Figure 14. Resistive load switching



- 1. Fast electronic switch
- 2. Non-inductive resistor

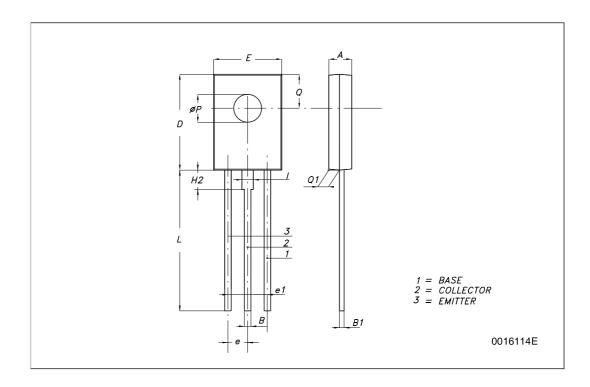
4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

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SOT-32 (TO-126) MECHANICAL DATA

DIM.	mm.		
	MIN.	TYP	MAX.
Α	2.4		2.9
В	0.64		0.88
B1	0.39		0.63
D	10.5		11.05
Е	7.4		7.8
е	2.04	2.29	2.54
e1	4.07	4.58	5.08
L	15.3		16
Р	2.9		3.2
Q		3.8	
Q1	1		1.52
H2		2.15	
Ţ		1.27	



Revision history ST83003

5 Revision history

Table 5. Document revision history

Date	Revision	Changes
16-Oct-2002	1	Initial release
08-Jul-2008	2	Mechanical data has been updated
08-Sep-2009	3	Updated packaging information Table 1 on page 1.
03-Dec-2010	4	Added Table 3: Thermal data on page 3.

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